

IN THE ABSTRACT:

Please replace the Abstract of the Disclosure originally filed with the above-identified patent application with the following amended Abstract of the Disclosure:

ABSTRACT OF THE DISCLOSURE

~~A. The present invention provides a surface acoustic wave sensor for detecting a target substance by measuring the change in frequency due to the mass applied to a reaction membrane placed on a surface acoustic wave element. The surface acoustic wave sensor has high sensitivity due to the improvement of the structure surface acoustic wave element.~~

—The surface acoustic wave sensor ~~includes~~uses an SH-type surface acoustic wave and ~~includes~~ a rotated Y-cut LiTaO₃ substrate having Euler angles (0°, 0° to 18°, 0° ± 5°) or (0°, 58° to 180°, 0° ± 5°); ~~electrodes-3, principally containing Au, for exciting a surface acoustic wave, the electrodes being arranged on the LiTaO₃ substrate-2; and a reaction membrane-4, bound to a target substance or a binding substance bound to the target substance, covering the electrodes-3 arranged on the LiTaO₃ substrate-2. The interdigital transducers-3 have a normalized thickness of about 0.8% to about 9.5%, the normalized thickness being determined by normalizing the thickness of the interdigital transducers-3 by the wavelength of the surface acoustic wave.~~